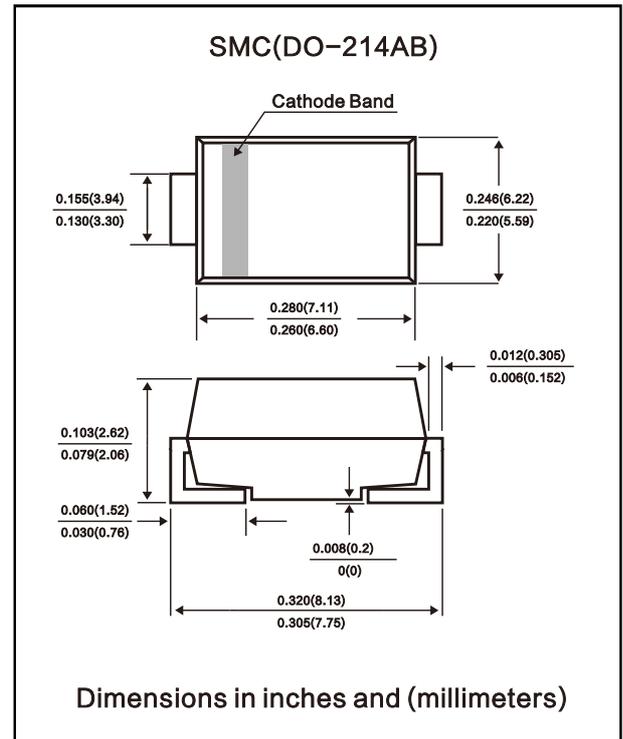


Features

- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Low Forward Voltage Drop, High Efficiency
- Surge Overload Rating to 100A Peak
- Low Power Loss
- Super-Fast Recovery Time
- Plastic Case Material has UL Flammability Classification Rating 94V-0

Mechanical Data

- Case: Low Profile Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.21 grams (approx.)


Maximum Ratings and Electrical Characteristics @ $T_A=25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	ER3A	ER3B	ER3C	ER3D	ER3E	ER3G	ER3J	Unit	
Peak Repetitive Reverse Voltage	V_{RRM}									
Working Peak Reverse Voltage	V_{RWM}	50	100	150	200	300	400	600	V	
DC Blocking Voltage	V_R									
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	105	140	210	280	420	V	
Average Rectified Output Current @ $T_L = 75^\circ\text{C}$	I_O	3.0								A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	100								A
Forward Voltage @ $I_F = 3.0\text{A}$	V_{FM}	0.95				1.25		1.7	V	
Peak Reverse Current @ $T_A = 25^\circ\text{C}$ At Rated DC Blocking Voltage @ $T_A = 100^\circ\text{C}$	I_{RM}					5.0			μA	
						500				
Reverse Recovery Time (Note 1)	t_{rr}					35			nS	
Typical Junction Capacitance (Note 2)	C_j					45			pF	
Typical Thermal Resistance (Note 3)	$R_{\theta JL}$					16			K/W	
Operating and Storage Temperature Range	T_j, T_{STG}	-65 to +150							$^\circ\text{C}$	

Note: 1. Measured with $I_F = 0.5\text{A}$, $I_R = 1.0\text{A}$, $I_{rr} = 0.25\text{A}$,
 2. Measured at 1.0 MHz and applied reverse voltage of 4.0 V DC.
 3. Mounted on P.C. Board with 8.0mm² land area.

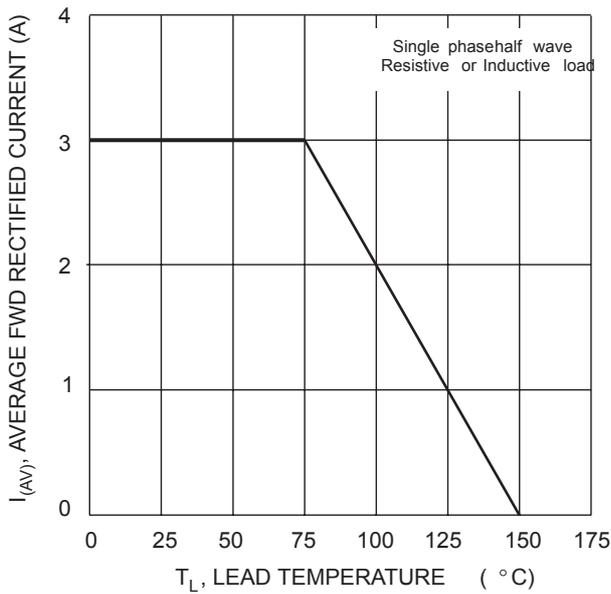


Fig. 1 Forward Current Derating Curve

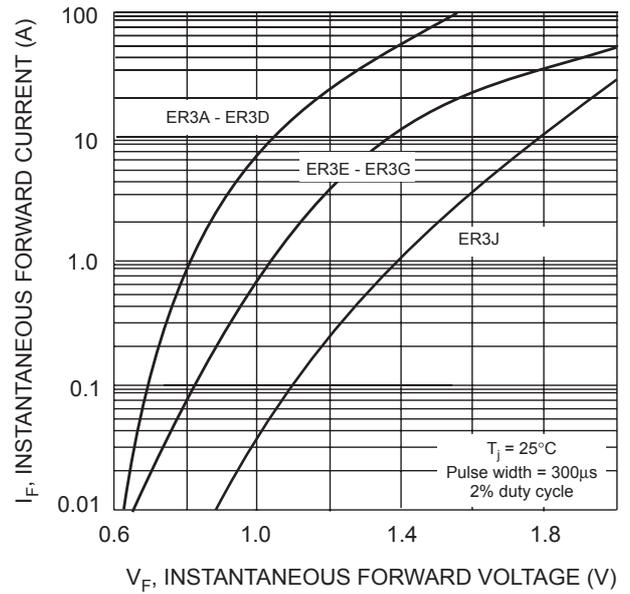


Fig. 2 Typical Forward Characteristics

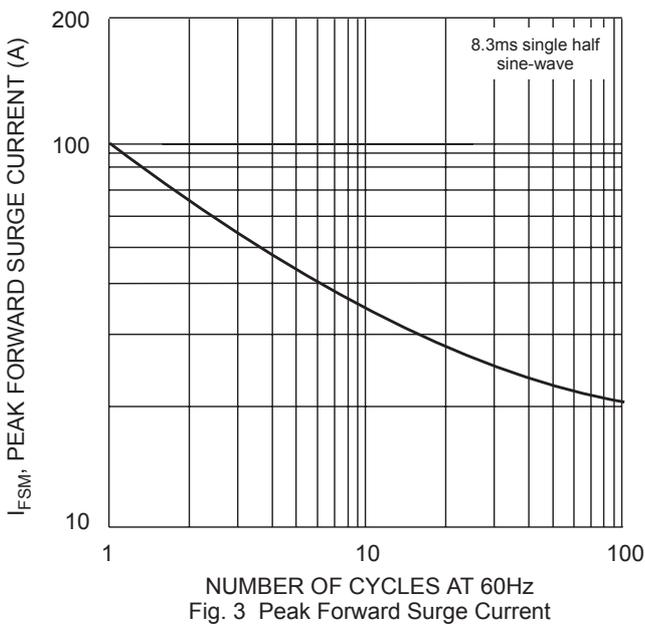


Fig. 3 Peak Forward Surge Current

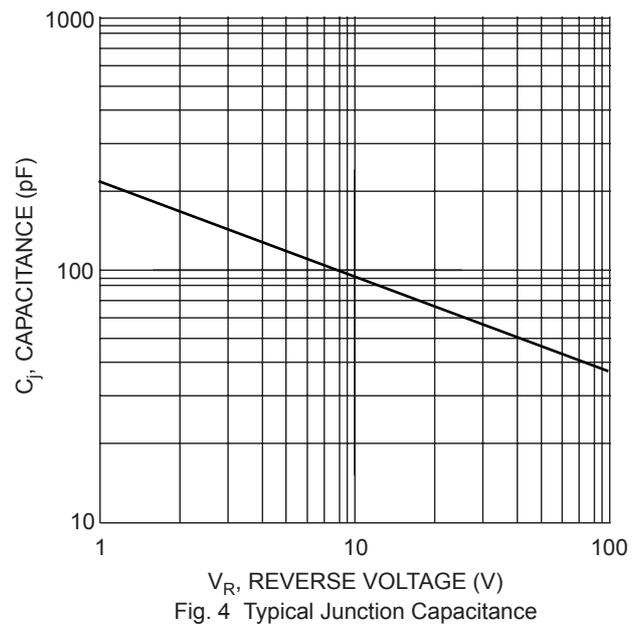
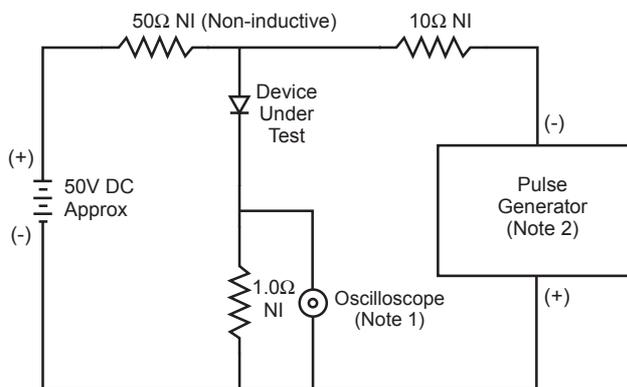
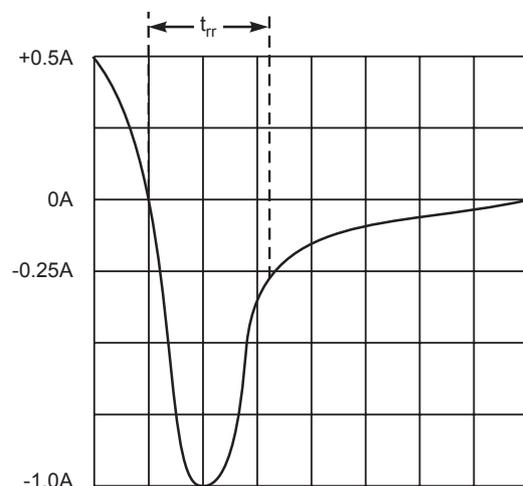


Fig. 4 Typical Junction Capacitance



- Notes:
1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
 2. Rise Time = 10ns max. Input Impedance = 50Ω.



Set time base for 5/10ns/cm

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit